

30V N-Channel MOSFET

1.Product Summary

V _{(BR)DSS}	R _{DS(on)TYP}	I _D
30V	10mΩ@10V	18A

2.Features

30V V_{DS} 18A I_D

 $R_{DS(ON)}$ (at $V_{GS}=10V$) <13 mohm

High density cell design for ultra low Rdson

Fully characterized avalanche voltage and current

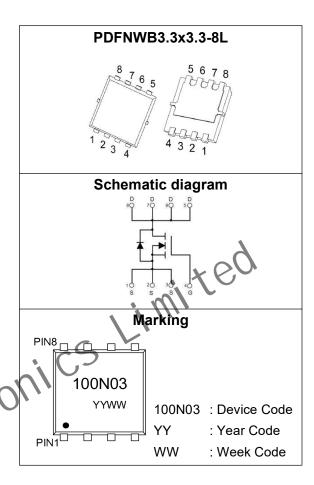
Good stability and uniformity with high EAS

Excellent package for good heat dissipation

Special process technology for high ESD capability

3.Applications

- **PWM Application**
- Load Switch
- **Power Management**



c Micro-Electron .Absolute Maximum rating $(T_A = 25^{\circ}C)$ unless otherwise noted

Parameter	Symbol	Value	Unit	
Drain - Source Voltage	V _{DS}	30	V	
Gate - Source Voltage		V _{GS}	±20	V
Continuous Drain Current		I _D	18	Α
Pulsed Drain Current	I _{DM}	54	Α	
Single Pulsed Avalanche Energy ¹		E _{AS}	52	mJ
Power Dissipation	T _C = 25°C	P _D	20	W
Thermal Resistance from Junction to Case	R _{θJC}	6.25	°C/W	
Junction Temperature	TJ	150	$^{\circ}$ C	
Storage Temperature	T _{STG}	-55~ +150	$^{\circ}$	



5.Electrical Characteristics ($T_A = 25$ °C unless otherwise noted)

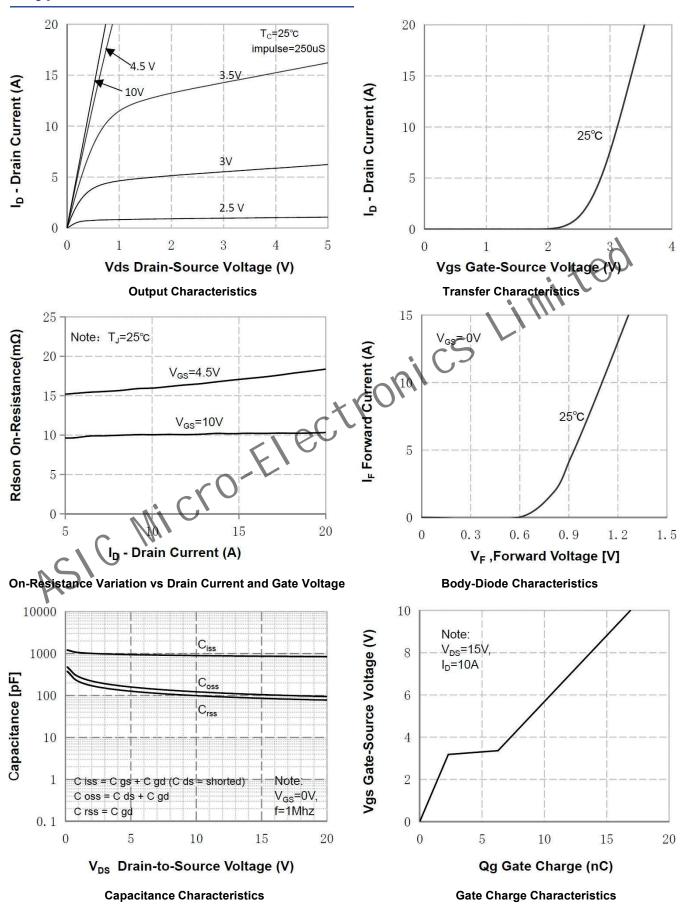
Parameter	Symbol	Test Condition	Min	Туре	Max	Unit		
Static Characteristics								
Drain - Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_{D} = 250\mu A$	30			V		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30V, V_{GS} = 0V$			1	μΑ		
Gate - Body Leakage Current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0	1.6	2.5	V		
Drain-source On-resistance ²	В	V _{GS} = 10V, I _D = 20A		10	13	mΩ		
Drain-source On-resistance-	R _{DS(on)}	V _{GS} = 4.5V, I _D = 10A		14	19	mΩ		
Dynamic Characteristics ³				•				
Input Capacitance	C _{iss}			865				
Output Capacitance	Coss	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1.0$		105	4	pF		
Reverse Transfer Capacitance	Crss	MHz		86	80			
Switching Characteristics ³	•		. 1	n I				
Total Gate Charge	Qg		1 /	17.2				
Gate-source Charge	Q _{gs}	$V_{DS} = 15V$, $I_{D} = 10A$, $V_{GS} = 10V$		2.7		nC		
Gate-drain Charge	Q _{gd}	100		4.0				
Turn-on Delay Time	t _{d(on)}	-01/1		5				
Turn-on Rise Time	t _r	V _{GS} =10V, V _{DS} =15V,		4				
Turn-off Delay Time	t _{d(off)}	R _L = 3Ω, I _D =10A, T _j =25°C		22		ns		
Turn-off Fall Time	t _f			6				
Source - Drain Diode Characteristic	Source - Drain Diode Characteristics							
Diode Forward Voltage ²	V _{SD}	V _{GS} = 0V, I _S = 10A			1.2	V		

Notes:

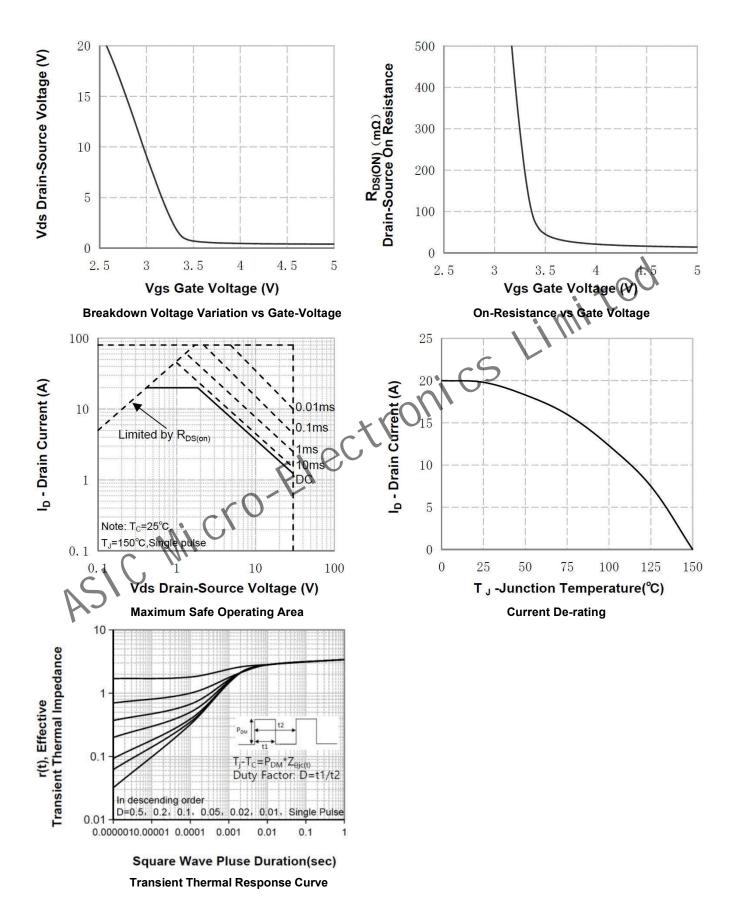
- 1. E_{AS} condition: V_{DD} =15V, V_{GS} =10V, L=0.5mH, R_g =25 Ω Starting T_J = 25° $^{\circ}$ C
- 2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 3. Guaranteed by design, not subject to production



6.Typical Characteristic

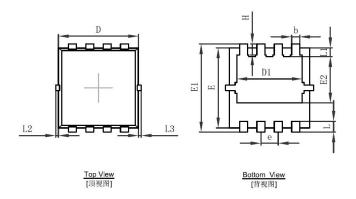


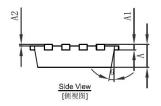




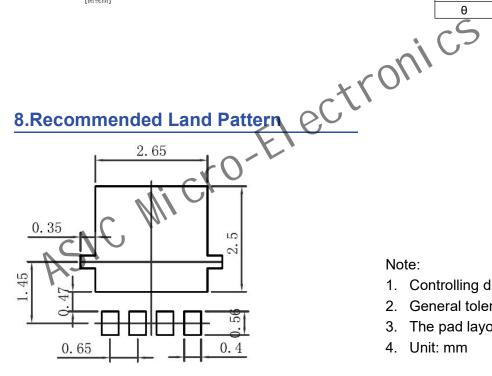


7.Dimension





Cumbal	Dimer	sions	Dimer	sions				
Symbol	Min	Max	Min	Max				
Α	0.650	0.850	0.026	0.033				
A1	0.152	REF.	0.006	REF.				
A2	0~0	0.05	0~0	.002				
D	2.900	3.100	0.114	0.122				
D1	2.300	2.600	0.091	0.102				
E	2.900	3.100	0.114	0.122				
E1	3.150	3.450	0.124	0.136				
E2	1.535	1.935	0.060	0.076				
b	0.200	0.400	0.008	0.016				
е	0.550	0.750	0.022	0.030				
L	0.300	0.500	0.012	0.020				
L1	0.180	0.480	0.007	0.019				
L2	0~0	.100	0~0	.004				
L3	0~0.100		0~0	.004				
H 4	0.315	0.515	0.012	0.020				
θ	9°	9° 13°		13°				



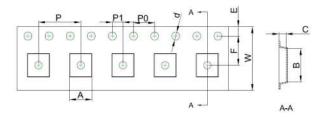
Note:

- 1. Controlling dimension: in millimeters
- 2. General tolerance: ±0.05mm
- 3. The pad layout is for reference only
- 4. Unit: mm



9. Tape and Reel

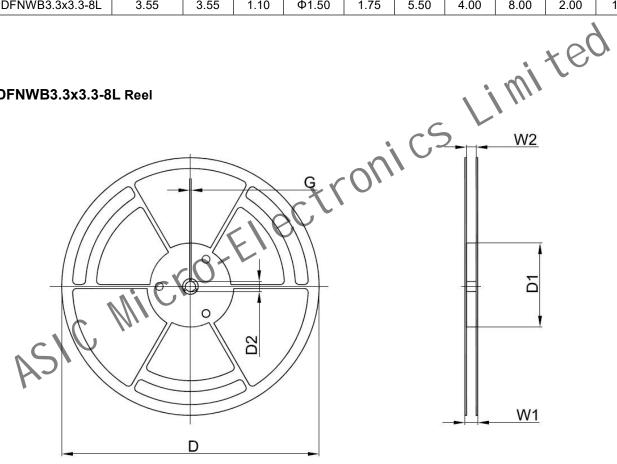
PDFNWB3.3x3.3-8L Embossed Carrier Tape



Packaging Description:
PDFNWB3.3x3.3-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated)

Dimensions are in millimeter								
Pkg type A B C d E F P0 P P1 W							W	
PDFNWB3.3x3.3-8L 3.55 3.55 1.10 Φ1.50 1.75 5.50 4.00 8.00 2.00 12.00								

PDFNWB3.3x3.3-8L Reel



Dimensions are in millimeter							
Reel Option D D1 D2 G W1 W2							
13``Dia	Ф330.00	100.00	13.00	1.90	17.60	12.40	

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	5.000 pcs	340x336x29	50,000 pcs	353x346x365



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